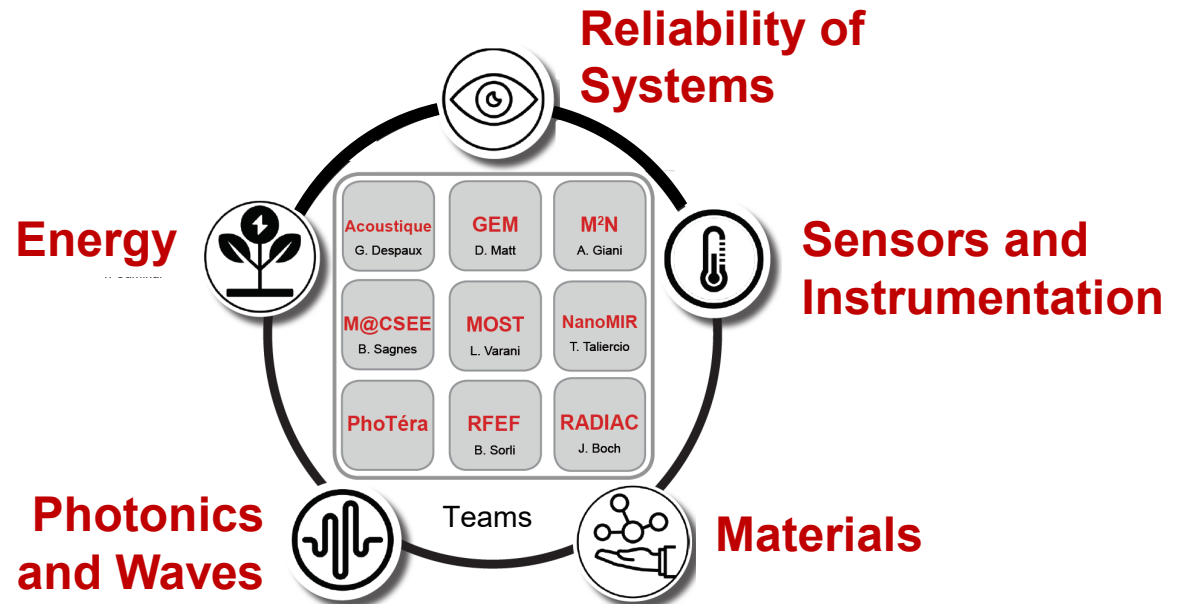


Institut d'Electronique et des Systèmes (Rodolphe Vaillon)

- > **240 people** (~100 permanent staff)
 - **5 axes, 9 teams**



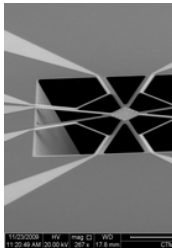
- **12 people** are involved in the GDR

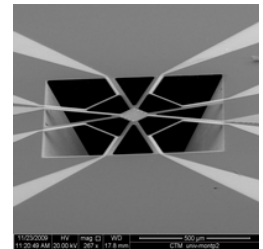
Institut d'Electronique et des Systèmes (Rodolphe Vaillon)

- **Areas of expertise:** components and systems in the fields of electronics, microelectronics, photonics, acoustics and energy conversion
- **CNRS section 8**
Micro- and nanotechnologies, micro- and nanosystems, photonics, electronics, electromagnetism, electrical energy
- **CNU section 63**
Electrical engineering, electronics, photonics and systems
- **Activity linked to every axis** of the network (elaboration, measurement of properties, measurement of device performances, simulation/theory)



Scientific expertise, overview, major themes in relation to the GDR

- Components and systems developed at IES involve both **physics** and **chemistry**
 - **Electrons**, **photons** and **phonons** all play a role in these components
 - Types of energy conversion:
photovoltaic, **thermophotovoltaic**, **thermoelectric**, **piezoelectric**
 - Targeted applications:
 - **Solar energy** harvesting (concentrated, indoors)
 - **Waste or stored heat** harvesting
 - **Sensors** and **detectors**
 - **Thermal management** in electronic devices
 - **Reliability** of devices (in **extreme conditions**, including high-temperature environments, under irradiation, under high illumination (CPV, TPV))
- 
- Thermal accelerometers



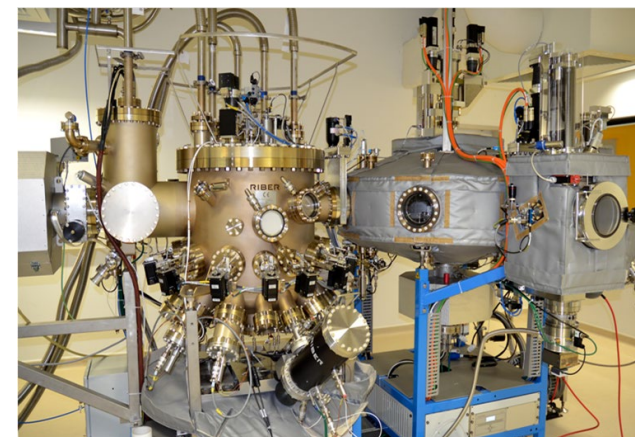
Thermal accelerometer

Technical or technological expertise in relation to the GDR issues

- Nano-materials: **super-lattices**, **thin films**, mostly made of
 - III-V semiconductors
 - Functional oxides
 - Bi_2Te_3 and Sb / Se containing alloys
 - Perovskites
- Both **bottom-up** and **top-down** approaches
- Elaboration techniques:
 - Solid **molecular beam epitaxy** (MBE)
 - **Soft chemistry**
 - Standard **clean-room processes**



Jolly et al., 2021



Ribier 412 MBE machine

Technical or technological expertise in relation to the GDR issues

- Main characterization techniques:
 - **Structural**: DDX, AFM
 - **Optical and electrical**: spectrophotometry, PL, I(V), C(V), Hall effect, Seebeck coefficient,...
- Special instruments:
 - **EquipEx EXTRA** ([EXcellence cenTeR on Antimonides](#)) devoted to the study and development of antimony-based III-V semiconductors (III-Sb) and their applications
 - **EquipEx+ HYBAT** (Hybrid Antimonide Technologies)
 - **Technological Centre for Micro- and Nano-electronics** ([CTM](#))
- In-house codes/numerical tools/modelling:
 - 1D and pseudo-3D solar cell [solvers](#)
- **New collaborations are most welcome!**

